# NSN 5962-01-298-3970

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-298-3970

# Body Length:

1.290 inches

# Body Width:

Between 0.500 inches and 0.610 inches

# **Body Height:**

Between 0.150 inches and 0.210 inches

# **Maximum Power Dissipation Rating:**

635.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Burn in and hermetically sealed and programmed and w/enable and ultraviolet erasable

#### Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

N-type metal oxide-semiconductor logic

## Input Circuit Pattern:

12 input

### Case Outline Source And Designator:

D-3 mil-m-38510

### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.0 volts power source

### **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, high to low level output and 450.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Prom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

### Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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